# REF5010, REF5020 REF5025, REF5030 REF5040, REF5045, REF5050

www.ti.com

## Low-Noise, Very Low Drift, Precision **VOLTAGE REFERENCE**

#### **FEATURES**

LOW TEMPERATURE DRIFT:

High-Grade: 3ppm/°C (max)

Standard-Grade: 8ppm/°C (max)

**HIGH ACCURACY:** 

 High-Grade: 0.05% (max) Standard-Grade: 0.1% (max)

LOW NOISE: 3µVpp/V

HIGH OUTPUT CURRENT: ±10mA

TEMPERATURE RANGE: -40°C to +125°C

#### **APPLICATIONS**

**16-BIT DATA ACQUISITION SYSTEMS** 

ATE EQUIPMENT

INDUSTRIAL PROCESS CONTROL

**MEDICAL INSTRUMENTATION** 

**OPTICAL CONTROL SYSTEMS** 

PRECISION INSTRUMENTATION

#### DESCRIPTION

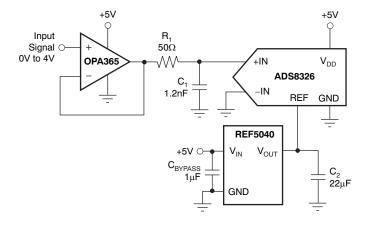
The REF50xx is a family of low-noise, low-drift, very high precision voltage references. These references are capable of both sinking and sourcing, and are very robust with regard to line and load changes.

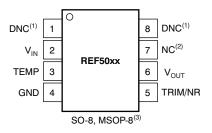
Excellent temperature drift (3ppm/°C) and high accuracy (0.05%) are achieved using proprietary design techniques. These features, combined with very-low noise make the REF50xx family ideal for use in high-precision data acquisition systems.

Each reference voltage is available in both standardand high-grade versions. They are offered in MSOP-8(3) and SO-8 packages, and are specified from -40°C to +125°C.

#### **REF50xx Family**

MODEL	OUTPUT VOLTAGE
REF5020	2.048V
REF5025	2.5V
REF5030	3.0V
REF5040	4.096V
REF5045	4.5V
REF5050	5.0V
REF5010 <sup>(4)</sup>	10.0V





NOTES: (1) DNC = Do not connect.

- (2) NC = No internal connection.
- (3) Contact a TI sales representative for information regarding MSOP-8 (DGK) package availability.
- (4) Available 4Q 2008.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

SBOS410B-JUNE 2007-REVISED SEPTEMBER 2008





www.ti.com



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### PACKAGE/ORDERING INFORMATION(1)

PRODUCT	OUTPUT VOLTAGE	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING		
STANDARD GRADE (8ppm, 0.1%	)	<u> </u>				
REF5020A	2.048V	SO-8	D	REF5020		
REF3020A	2.048V	MSOP-8 <sup>(2)</sup>	DGK	R50A		
REF5025A	2.5V	SO-8	D	REF5025		
KEF3025A	2.50	MSOP-8 <sup>(2)</sup>	DGK	R50B		
REF5030A	3.0V	SO-8	D	REF5030		
REFOUGUA	3.0V	MSOP-8 <sup>(2)</sup>	DGK	R50C		
REF5040A	4.096V	SO-8	D	REF5040		
REF5040A	4.096V	MSOP-8 <sup>(2)</sup>	DGK	R50D		
DEECOASA	45)/	SO-8	D	REF5045		
REF5045A	4.5V	MSOP-8 <sup>(2)</sup>	DGK	R50E		
DEECOSOA	5.0V	SO-8	D	REF5050		
REF5050A	5.00	MSOP-8 <sup>(2)</sup>	DGK	R50F		
REF5010A <sup>(3)</sup>	40.01/	SO-8	D	REF5010		
REF5010A <sup>(6)</sup>	10.0V	MSOP-8 <sup>(2)</sup>	DGK	R50G		
HIGH GRADE (3ppm, 0.05%)		<u> </u>				
DEFFOOOL	0.040\/	SO-8	D	REF5020		
REF5020I	2.048V	MSOP-8 <sup>(2)</sup>	DGK	R50A		
DEFFORM	0.577	SO-8	D	REF5025		
REF5025I	2.5V	MSOP-8 <sup>(2)</sup>	DGK	R50B		
REF5030I	3.0V	SO-8	D	REF5030		
REF5030I	3.0V	MSOP-8 <sup>(2)</sup>	DGK	R50C		
DEE50401	4.0001/	SO-8	D	REF5040		
REF5040I	4.096V	MSOP-8 <sup>(2)</sup>	DGK	R50D		
DEFENSE	4.5\/	SO-8	D	REF5045		
REF5045I	4.5V	MSOP-8 <sup>(2)</sup>	DGK	R50E		
DEFECTO	5.07	SO-8	D	REF5050		
REF5050I	5.0V	MSOP-8 <sup>(2)</sup>	DGK	R50F		
REF5010I <sup>(3)</sup>	40.01/	SO-8	D	REF5010		
KEF5010I®	10.0V	MSOP-8 <sup>(2)</sup>	DGK	R50G		

<sup>(1)</sup> For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

### ABSOLUTE MAXIMUM RATINGS(1)

PARAMETER		REF50xx	UNIT
Input Voltage		+18	V
Output Short-Circu	it	30	mA
Operating Tempera	ature Range	–55 to +125	°C
Storage Temperate	ure Range	–55 to +150	°C
Junction Temperat	rure (T <sub>J</sub> max)	+150	°C
CCD Dating	Human Body Model (HBM)	3000	V
ESD Rating	Charged Device Model (CDM)	1000	V

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

Contact a TI sales representative for information regarding MSOP-8 (DGK) package availability.

Available 4Q 2008.



#### **ELECTRICAL CHARACTERISTICS: PER DEVICE**

**Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ . At  $T_A = +25^{\circ}C$ ,  $I_{LOAD} = 0$ ,  $C_L = 1\mu F$ , and  $V_{IN} = (V_{OUT} + 0.2V)$  to 18V, unless otherwise noted.

				PER DEVICE			
	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT	
		REF5020 (V <sub>OUT</sub> = 2.048V) <sup>(1)</sup>		1	I		
OUTPUT VOLTAG							
Output Voltage	V <sub>out</sub>	2.7V < V <sub>IN</sub> < 18V		2.048		V	
Initial Accuracy:	High-Grade		-0.05		0.05	%	
	Standard-Grade		-0.1		0.1	%	
NOISE							
Output Voltage No	ise	f = 0.1Hz to 10Hz		6		$\mu V_{PP}$	
		REF5025 (V <sub>OUT</sub> = 2.5V)					
OUTPUT VOLTAG				0.5		.,	
Output Voltage	V <sub>OUT</sub>		0.05	2.5	0.05	V	
Initial Accuracy:	High-Grade		-0.05		0.05	%	
	Standard-Grade		-0.1		0.1	%	
NOISE		6 0 411 + 4011				.,	
Output Voltage No	ise	f = 0.1Hz to 10Hz		7.5		$\mu V_{PP}$	
OUTDUT VOLTAG	25	REF5030 (V <sub>OUT</sub> = 3.0V)					
Output Voltage				3.0		V	
Output Voltage	V <sub>OUT</sub>		0.05	3.0	0.05		
Initial Accuracy:	High-Grade Standard-Grade		-0.05		0.05	%	
NOISE	Standard-Grade		-0.1		0.1	%	
NOISE	:	f 0.4H= += 40H=		9			
Output Voltage No	ise	f = 0.1Hz to 10Hz REF5040 (V <sub>OUT</sub> = 4.096V)		9		$\mu V_{PP}$	
OUTPUT VOLTAG	>r	REF3040 (V <sub>OUT</sub> = 4.096V)					
				4.000		\/	
Output Voltage	V <sub>OUT</sub>		-0.05	4.096	0.05	V %	
Initial Accuracy:	High-Grade Standard-Grade		-0.05 -0.1		0.03	%	
NOISE	Standard-Grade		-0.1		0.1	70	
Output Voltage No	ico	f = 0.1Hz to 10Hz		12		μV <sub>PP</sub>	
Output Voltage 140	130	REF5045 (V <sub>OUT</sub> = 4.5V)		12		μνрр	
OUTPUT VOLTAG	SE.	(VOUT = 4.54)					
Output Voltage	V <sub>OUT</sub>			4.5		V	
Initial Accuracy:	High-Grade		-0.05	4.0	0.05	%	
miliai 7 locuracy.	Standard-Grade		-0.1		0.1	%	
NOISE			· · ·		5	,,,	
Output Voltage No	ise	f = 0.1Hz to 10Hz		13.5		μV <sub>PP</sub>	
,		REF5050 (V <sub>OUT</sub> = 5.0V)			I	F** FP	
OUTPUT VOLTAG	SE	, 301 ,					
Output Voltage	V <sub>OUT</sub>			5.0		V	
Initial Accuracy:	High-Grade		-0.05		0.05	%	
	Standard-Grade		-0.1		0.1	%	
NOISE							
Output Voltage No	ise	f = 0.1Hz to 10Hz		15		μV <sub>PP</sub>	
		REF5010 (V <sub>OUT</sub> = 10.0V) <sup>(2)</sup>	1	1	<u> </u>		
OUTPUT VOLTAG	GE .	, ,					
Output Voltage	V <sub>out</sub>			10.0		V	
Initial Accuracy:	High-Grade		-0.05		0.05	%	
	Standard-Grade		-0.1		0.1	%	
NOISE							
			1	1	1	1	

For  $\rm V_{OUT} \le 2.5V,$  the minimum supply voltage is 2.7V. Available 4Q 2008.



#### **ELECTRICAL CHARACTERISTICS: ALL DEVICES**

**Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ . At  $T_A = +25^{\circ}C$ ,  $I_{LOAD} = 0$ ,  $C_L = 1\mu F$ , and  $V_{IN} = (V_{OUT} + 0.2V)$  to 18V, unless otherwise noted.

			F	REF50xx			
PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT	
OUTPUT VOLTAGE TEMPERATURE	DRIFT						
Output Voltage Temperature Drift	dV <sub>OUT</sub> /dT						
High-Grade				2.5	3	ppm/°C	
Standard-Grade				3	8	ppm/°C	
LINE REGULATION							
Line Regulation	$\mathrm{dV}_{\mathrm{OUT}}/\mathrm{dV}_{\mathrm{IN}}$						
REF5020 <sup>(1)</sup> Only		$V_{IN} = 2.7V \text{ to } 18V$		0.1	1	ppm/V	
All Other Devices				0.1	1	ppm/V	
Over Temperature				0.2	1	ppm/V	
LOAD REGULATION							
Load Regulation	$\mathrm{dV}_{\mathrm{OUT}}/\mathrm{d}_{\mathrm{ILOAD}}$	$-10\text{mA} < I_{\text{LOAD}} < +10\text{mA}, \ V_{\text{IN}} = V_{\text{OUT}} + 0.75\text{V}$		20	30	ppm/mA	
Over Temperature					50	ppm/mA	
SHORT-CIRCUIT CURRENT							
Short-Circuit Current	I <sub>SC</sub>	$V_{OUT} = 0$		25		mA	
TEMP PIN							
Voltage Output		At $T_A = +25$ °C		575		mV	
Temperature Sensitivity				2.64		mV/°C	
TURN-ON SETTLING TIME							
Turn-On Settling Time		To 0.1% with $C_L = 1\mu F$		200		μs	
POWER SUPPLY							
Supply Voltage	Vs	See Note (1)	$V_{OUT} + 0.2^{(1)}$		18	V	
Quiescent Current				0.8	1	mA	
Over Temperature					1.2	mA	
TEMPERATURE RANGE							
Specified Range			-40		+125	°C	
Operating Range			<b>-</b> 55		+125	°C	
Thermal Resistance	$\theta_{JA}$						
MSOP-8				150		°C/W	
SO-8				150		°C/W	

<sup>(1)</sup> For  $V_{OUT} \le 2.5V$ , the minimal supply voltage is 2.7V.



#### TYPICAL CHARACTERISTICS

At  $T_A = +25^{\circ}C$ ,  $I_{LOAD} = 0$ , and  $V_S = V_{OUT} + 0.2V$ , unless otherwise noted. For  $V_{OUT} \le 2.5V$ , the minimum supply voltage is 2.7V.

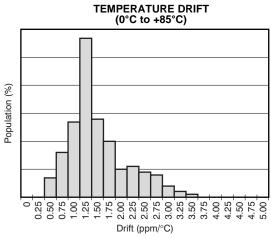


Figure 1.

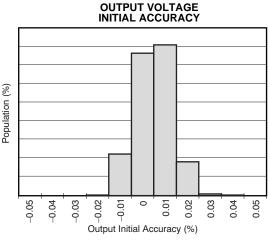
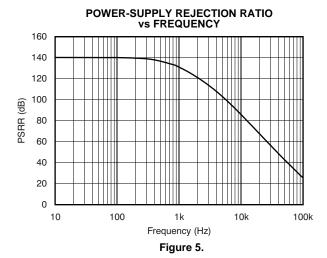


Figure 3.



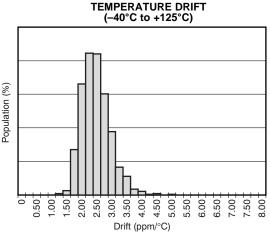


Figure 2.

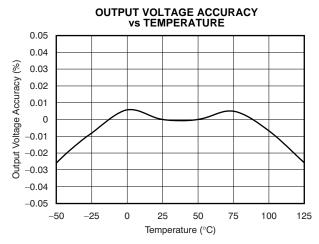


Figure 4.

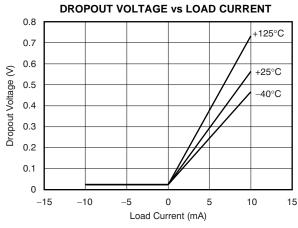
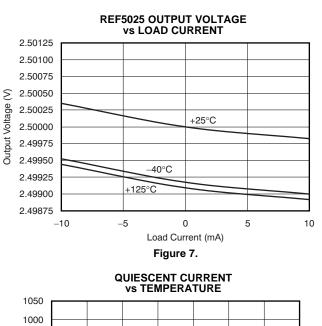


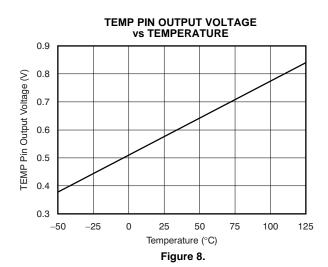
Figure 6.

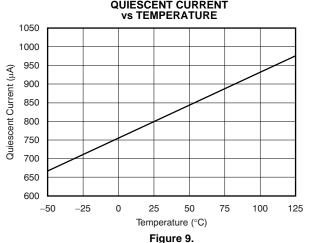


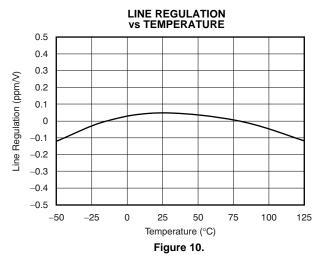
#### **TYPICAL CHARACTERISTICS (continued)**

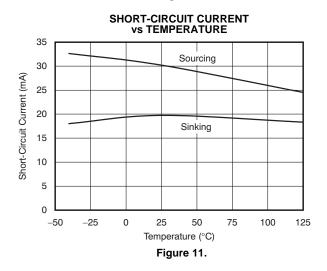
At  $T_A = +25$ °C,  $I_{LOAD} = 0$ , and  $V_S = V_{OUT} + 0.2V$ , unless otherwise noted. For  $V_{OUT} \le 2.5V$ , the minimum supply voltage is 2.7V.











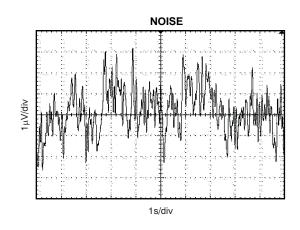
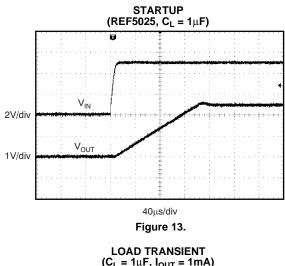


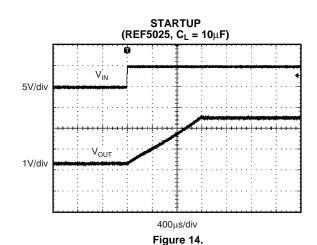
Figure 12.

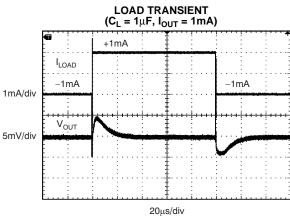


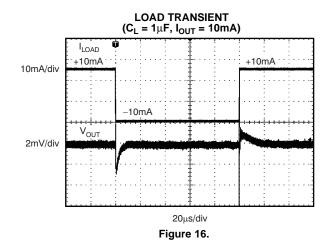
#### **TYPICAL CHARACTERISTICS (continued)**

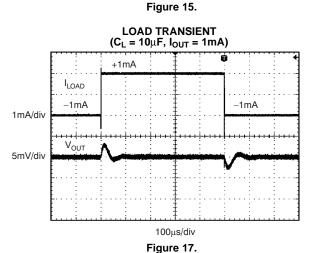
At  $T_A = +25$ °C,  $I_{LOAD} = 0$ , and  $V_S = V_{OUT} + 0.2V$ , unless otherwise noted. For  $V_{OUT} \le 2.5V$ , the minimum supply voltage is 2.7V.











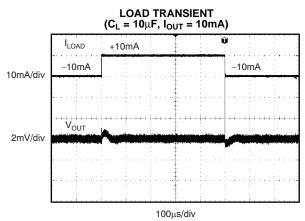
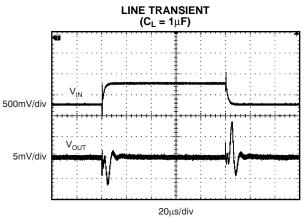


Figure 18.



#### **TYPICAL CHARACTERISTICS (continued)**

At  $T_A = +25$ °C,  $I_{LOAD} = 0$ , and  $V_S = V_{OUT} + 0.2V$ , unless otherwise noted. For  $V_{OUT} \le 2.5V$ , the minimum supply voltage is 2.7V.



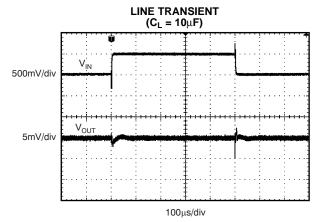


Figure 20.



#### APPLICATION INFORMATION

The REF50xx is family of low-noise, precision bandgap voltage references that are specifically designed for excellent initial voltage accuracy and drift. Figure 21 shows a simplified block diagram of the REF50xx.

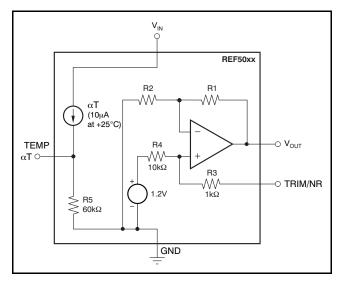


Figure 21. REF50xx Simplified Block Diagram

#### **BASIC CONNECTIONS**

Figure 22 shows the typical connections for the REF50xx. A supply bypass capacitor ranging between  $1\mu F$  to  $10\mu F$  is recommended. A  $1\mu F$  to  $50\mu F$  output capacitor (C<sub>L</sub>) must be connected from V<sub>OUT</sub> to GND. The ESR value of C<sub>L</sub> must be less than or equal to  $1.5\Omega$  to ensure output stability. To minimize noise, the recommended ESR of C<sub>L</sub> is between  $1\Omega$  and  $1.5\Omega$ .

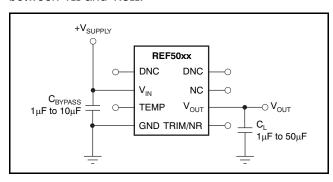


Figure 22. Basic Connections

#### SUPPLY VOLTAGE

The REF50xx family of voltage references features extremely low dropout voltage. With the exception of the REF5020, which has a minimum supply requirement of 2.7V, these references can be operated with a supply of 200mV above the output voltage in an unloaded condition. For loaded conditions, a typical dropout voltage versus load plot is shown in Figure 6 of the Typical Characteristics.

# OUTPUT ADJUSTMENT USING THE TRIM/NR PIN

The REF50xx provides a very accurate, factory-trimmed voltage output. However,  $V_{OUT}$  can be adjusted using the trim and noise reduction pin (TRIM/NR, pin 5). Figure 23 shows a typical circuit that allows an output adjustment of  $\pm 15$ mV

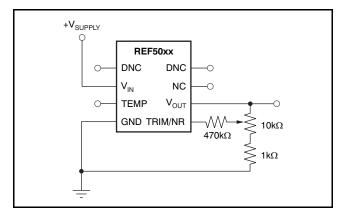


Figure 23. V<sub>OUT</sub> Adjustment Using the TRIM/NR

The REF50xx allows access to the bandgap through the TRIM/NR pin. Placing a capacitor from the TRIM/NR pin to GND (see Figure 24) in combination with the internal  $R_3$  and  $R_4$  resistors creates a low-pass filter. A capacitance of  $1\mu F$  creates a low-pass filter with the corner frequency between 10Hz and 20Hz. Such a filter decreases the overall noise measured on the  $V_{\text{OUT}}$  pin by half. Higher capacitance results in a lower filter cutoff frequency, further reducing output noise. Note that use of this capacitor increases startup time.

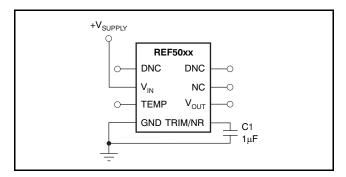


Figure 24. Noise Reduction Using the TRIM/NR

#### **TEMPERATURE DRIFT**

The REF50xx is designed for minimal drift error, which is defined as the change in output voltage over temperature. The drift is calculated using the box method, as described by the following equation:

Drift = 
$$\left(\frac{V_{OUTMAX} - V_{OUTMIN}}{V_{OUT} \times Temp Range}\right) \times 10^{6} (ppm)$$
 (1)

The REF50xx features a maximum drift coefficient of 3ppm/°C for the high-grade version, and 8ppm/°C for the standard-grade.

#### **TEMPERATURE MONITORING**

The temperature output terminal (TEMP, pin 3) provides a temperature-dependent voltage output with approximately  $60k\Omega$  source impedance. As seen in Figure 8, the output voltage follows the nominal relationship:

$$V_{TEMP\ PIN} = 509mV + 2.64 \times T(^{\circ}C)$$

This pin indicates general chip temperature, accurate to approximately ±15°C. Although it is not generally suitable for accurate temperature measurements, it can be used to indicate temperature changes or for temperature compensation of analog circuitry. A temperature change of 30°C corresponds to an approximate 79mV change in voltage at the TEMP pin.

The TEMP pin has high output impedance (see Figure 21). Loading this pin with a low-impedance circuit induces a measurement error; however, it does not have any effect on V<sub>OUT</sub> accuracy. To avoid errors caused by low-impedance loading, buffer the TEMP pin output with a suitable low-temperature drift op amp, such as the OPA333, OPA335, or OPA376, as shown in Figure 25.

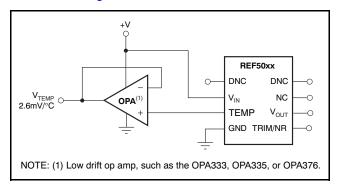


Figure 25. Buffering the TEMP Pin Output

#### POWER DISSIPATION

The REF50xx family is specified to deliver current loads of ±10mA over the specified input voltage range. The temperature of the device increases according to the equation:

$$T_J = T_A + P_D \times \theta_{JA}$$

Where:

 $T_J = Junction temperature (°C)$ 

 $T_A$  = Ambient temperature (°C)

 $P_D$  = Power dissipated (W)

 $\theta_{JA}$  = Junction-to-ambient thermal resistance (°C/W)

The REF50xx junction temperature must not exceed the absolute maximum rating of +150°C.

#### **NOISE PERFORMANCE**

Typical 0.1Hz to 10Hz voltage noise for each member of the REF50xx family is specified in the *Electrical Characteristics: Per Device* table. The noise voltage increases with output voltage and operating temperature. Additional filtering can be used to improve output noise levels, although care should be taken to ensure the output impedance does not degrade performance.



#### **APPLICATION CIRCUITS**

#### **NEGATIVE REFERENCE VOLTAGE**

For applications requiring a negative and positive reference voltage, the REF50xx and OPA735 can be used to provide a dual-supply reference from a 5V supply. Figure 26 shows the REF5025 used to provide a 2.5V supply reference voltage. The low drift performance of the REF50xx complements the low offset voltage and zero drift of the OPA735 to provide an accurate solution for split-supply applications. Care must be taken to match the temperature coefficients of  $R_1$  and  $R_2$ .

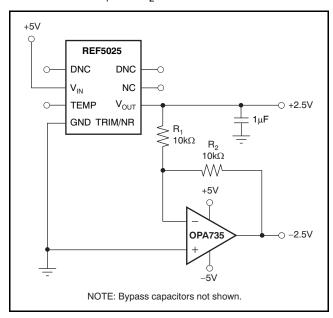


Figure 26. The REF5025 and OPA735 Create Positive and Negative Reference Voltages

#### DATA ACQUISITION

Data acquisition systems often require stable voltage references to maintain accuracy. The REF50xx family features low noise, very low drift, and high initial accuracy for high-performance data converters. Figure 27 shows the REF5040 in a basic data acquisition system.

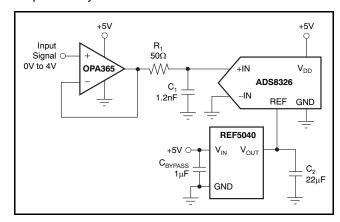


Figure 27. Basic Data Acquisition System



#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
REF5010AID	PREVIEW	SOIC	D	8	75	TBD	Call TI	Call TI
REF5010AIDGKR	PREVIEW	MSOP	DGK	8	2500	TBD	Call TI	Call TI
REF5010AIDGKT	PREVIEW	MSOP	DGK	8	250	TBD	Call TI	Call TI
REF5010AIDR	PREVIEW	SOIC	D	8	2500	TBD	Call TI	Call TI
REF5010ID	PREVIEW	SOIC	D	8	75	TBD	Call TI	Call TI
REF5010IDGKR	PREVIEW	MSOP	DGK	8	2500	TBD	Call TI	Call TI
REF5010IDGKT	PREVIEW	MSOP	DGK	8	250	TBD	Call TI	Call TI
REF5010IDR	PREVIEW	SOIC	D	8	2500	TBD	Call TI	Call TI
REF5020AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5020AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5020AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5020IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5025AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5025AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5025IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5030AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5030AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS &	CU NIPDAU	Level-2-260C-1 YEAR
-							-	





om 16-Oct-2008

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3</sup>
						no Sb/Br)		
REF5030AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5030AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5030AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAF
REF5030AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5030ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5030IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5030IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5030IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5040AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5040AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5040IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5045AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5045AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
REF5045IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS &	CU NIPDAU	Level-2-260C-1 YEA





16-Oct-2008

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp (3)
						no Sb/Br)		
REF5050AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050AIDGKR	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5050AIDGKT	PREVIEW	MSOP	DGK	8		TBD	Call TI	Call TI
REF5050AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
REF5050IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

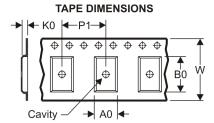
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

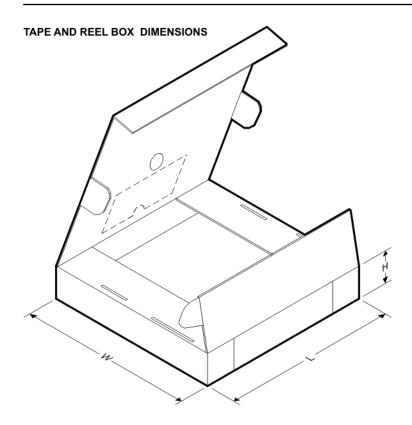
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF5020AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5020IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5025AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5025IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5030AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5030IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5040AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5040IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5045AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5045IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5050AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
REF5050IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF5020AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5020IDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5025AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5025IDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5030AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5030IDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5040AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5040IDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5045AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5045IDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5050AIDR	SOIC	D	8	2500	346.0	346.0	29.0
REF5050IDR	SOIC	D	8	2500	346.0	346.0	29.0

## D (R-PDSO-G8)

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



## DGK (S-PDSO-G8)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

#### **Products Amplifiers** amplifier.ti.com Data Converters dataconverter.ti.com DSP dsp.ti.com Clocks and Timers www.ti.com/clocks Interface interface.ti.com Logic logic.ti.com Power Mgmt power.ti.com Microcontrollers microcontroller.ti.com www.ti-rfid.com RF/IF and ZigBee® Solutions www.ti.com/lprf

Applications	
Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Medical	www.ti.com/medical
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated